

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
60V	29mΩ@10V	18A
	35mΩ@4.5V	

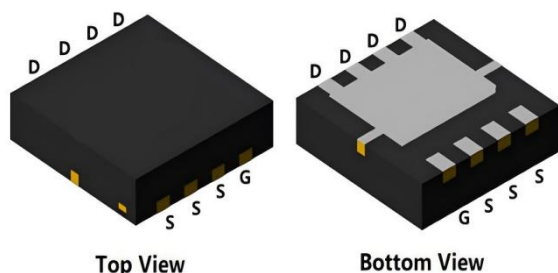
Feature

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Suffix "-Q1" for AEC-Q101

Application

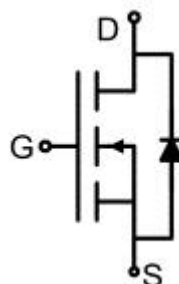
- DC-DC converter
- Power switching application
- Uninterruptible power supply

Package

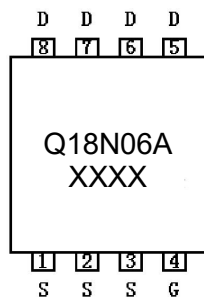


DFN3.3*3.3-8L

Circuit diagram



Marking



Absolute maximum ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ($T_C=25^{\circ}\text{C}$)	I_D	18	A
Continuous Drain Current ($T_C=100^{\circ}\text{C}$)	$I_D (100^{\circ}\text{C})$	11	A
Pulsed Drain Current ¹⁾	I_{DM}	60	A
Single Pulse Avalanche Energy ²⁾	E_{AS}	36	mJ
Power Dissipation ³⁾ ($T_C=25^{\circ}\text{C}$)	P_D	18.5	W
Thermal Resistance Junction to Case	$R_{\theta JC}$	6.7	$^{\circ}\text{C/W}$
Operating Junction Temperature	T_J	$-55 \sim +150$	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

Electrical characteristics ($T_J=25^{\circ}\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	60			V
Zero gate voltage drain current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.5	2.5	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=18A$		22	29	m Ω
		$V_{GS}=4.5V, I_D=15A$		26	35	
Dynamic characteristics ⁴⁾						
Input Capacitance	C_{iss}	$V_{DS}=30V, V_{GS}=0V, f=1MHz$		1180		pF
Output Capacitance	C_{oss}			65		
Reverse Transfer Capacitance	C_{rss}			55		
Total Gate Charge	Q_g	$V_{DS}=30V, V_{GS}=10V, I_D=20A$		23		nC
Gate-Source Charge	Q_{gs}			3		
Gate-Drain Charge	Q_{gd}			6		
Turn-on delay time	$t_{d(on)}$	$V_{DS}=30V, V_{GS}=10V, I_D=20A$ $R_G=2.2\Omega$		5		nS
Turn-on rise time	t_r			45		
Turn-off delay time	$t_{d(off)}$			19		
Turn-off fall time	t_f			2		
Source-Drain Diode characteristics						
Diode Forward Current	I_S				18	A
Diode Forward voltage	V_{SD}	$V_{GS}=0V, I_S=18A$			1.2	V
Reverse Recovery Time	T_{rr}	$I_F=20A, di/dt=100A/\mu s$		23.5		nS
Reverse Recovery Charge	Q_{rr}			17.5		nC

Notes:

- 1) Repetitive rating; pulse width limited by max. junction temperature.
- 2) $T_J=25^{\circ}\text{C}$, $V_G=10V$, $R_G=25\Omega$, $L=0.5\text{mH}$, $I_{AS}=12A$.
- 3) P_d is based on max. junction temperature, using junction-case thermal resistance.
- 4) Guaranteed by design, not subject to production testing.

Typical Characteristics

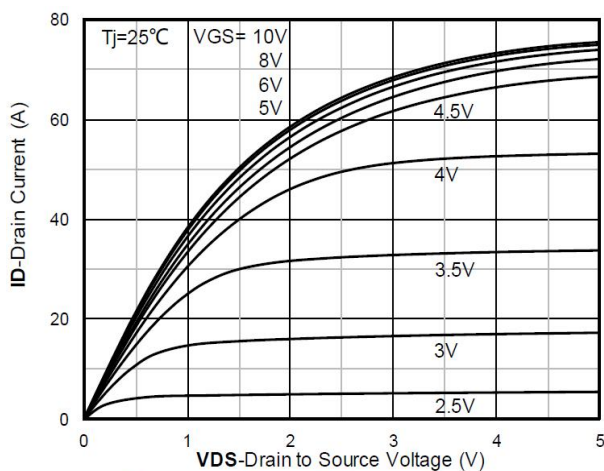


Figure 1. Output Characteristics

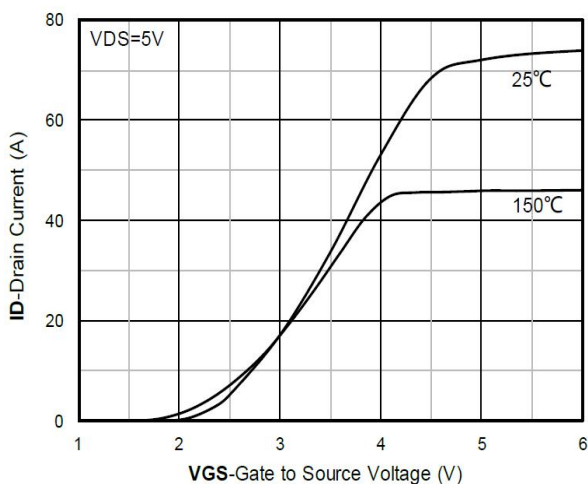


Figure 2. Transfer Characteristics

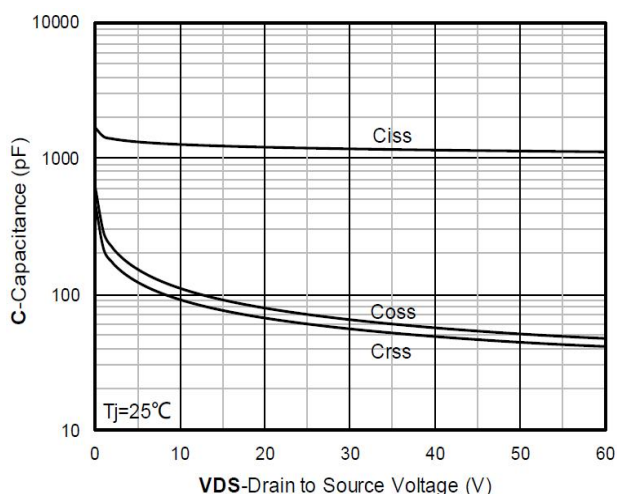


Figure 3. Capacitance Characteristics

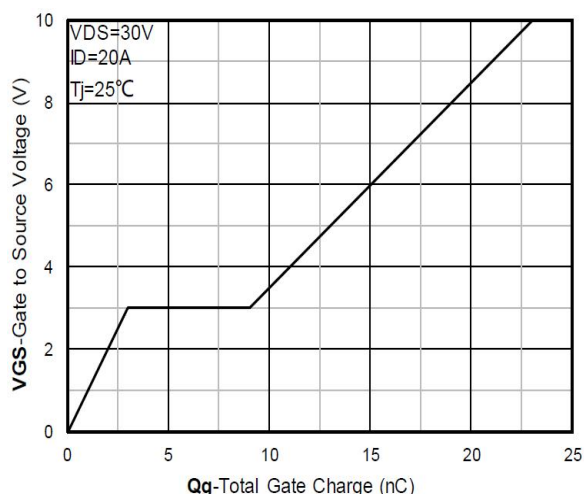


Figure 4. Gate Charge

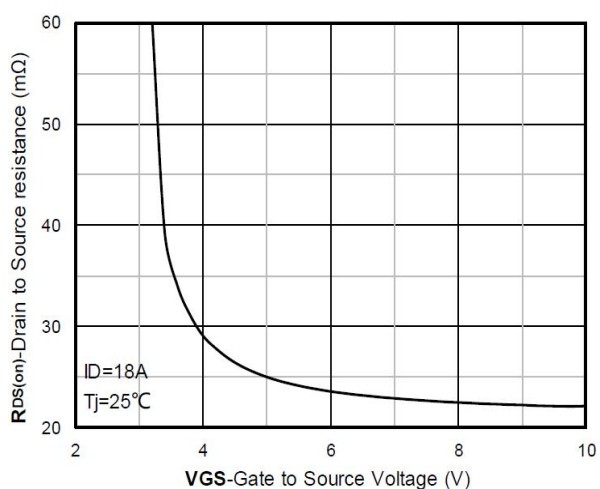


Figure 5. On-Resistance vs Gate to Source Voltage

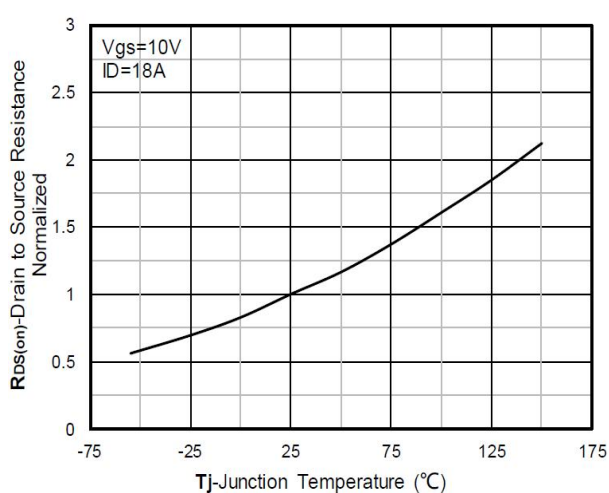


Figure 6. Normalized On-Resistance

Typical Characteristics

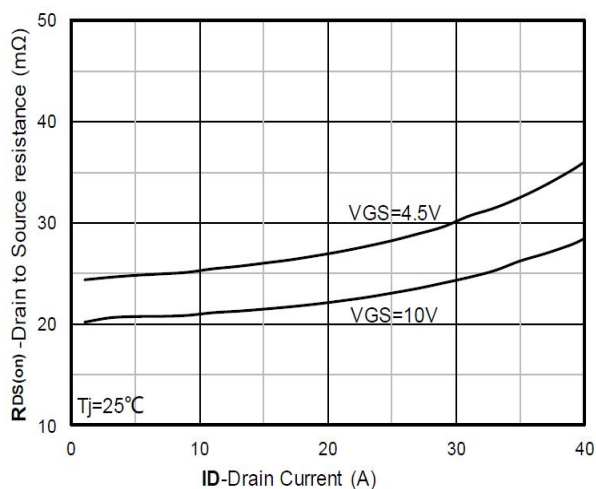


Figure 7. RDS(on) VS Drain Current

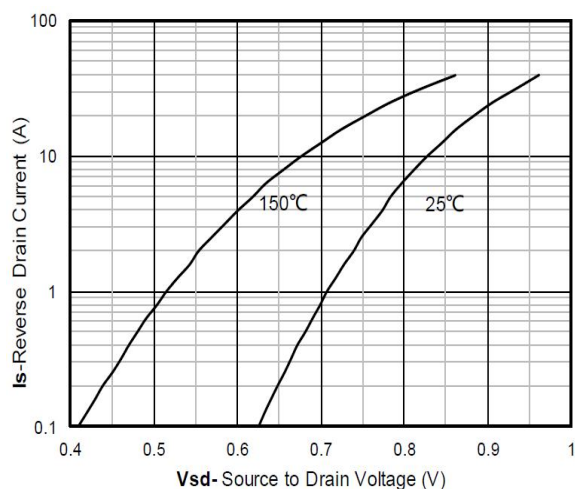


Figure 8. Forward characteristics of reverse diode

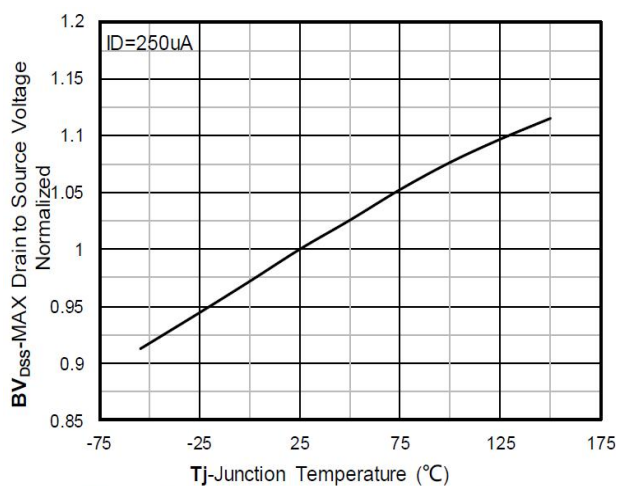


Figure 9. Normalized breakdown voltage

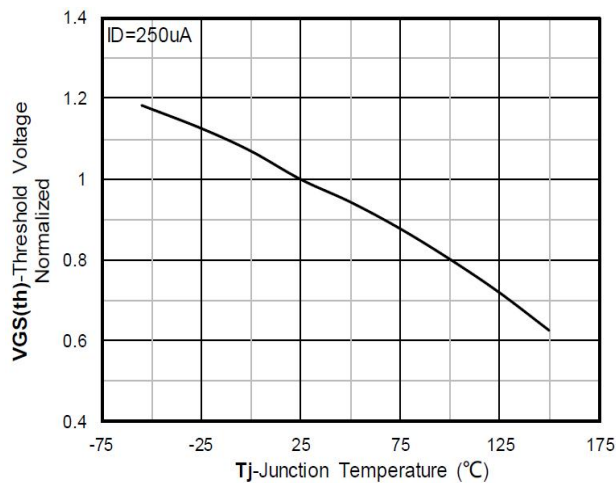


Figure 10. Normalized Threshold voltage

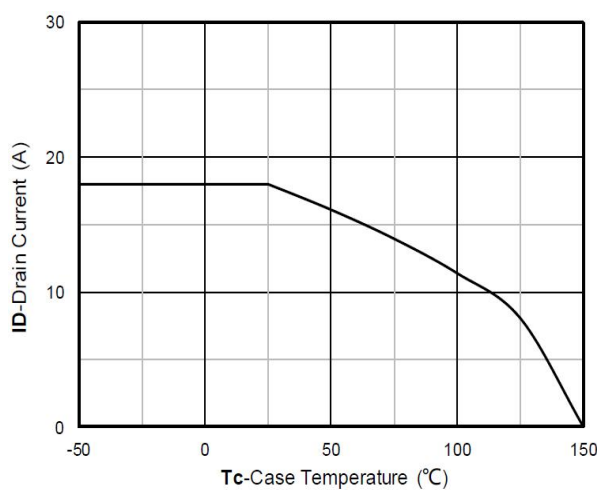


Figure 11. Current dissipation

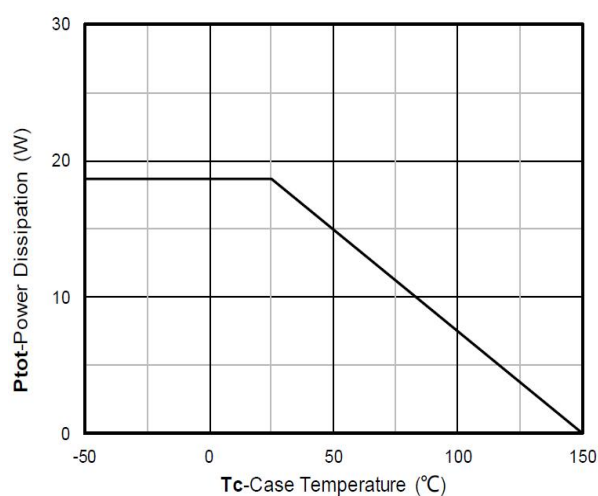


Figure 12. Power dissipation

Typical Characteristics

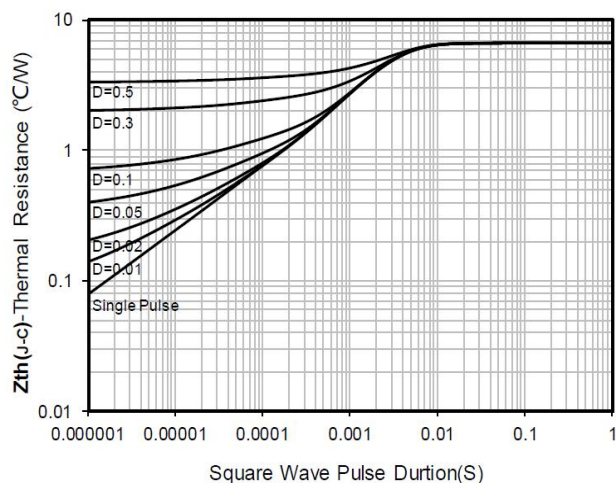


Figure 13. Maximum Transient Thermal Impedance

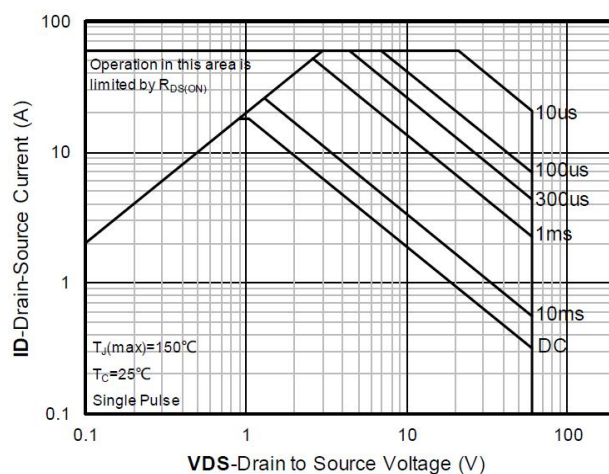
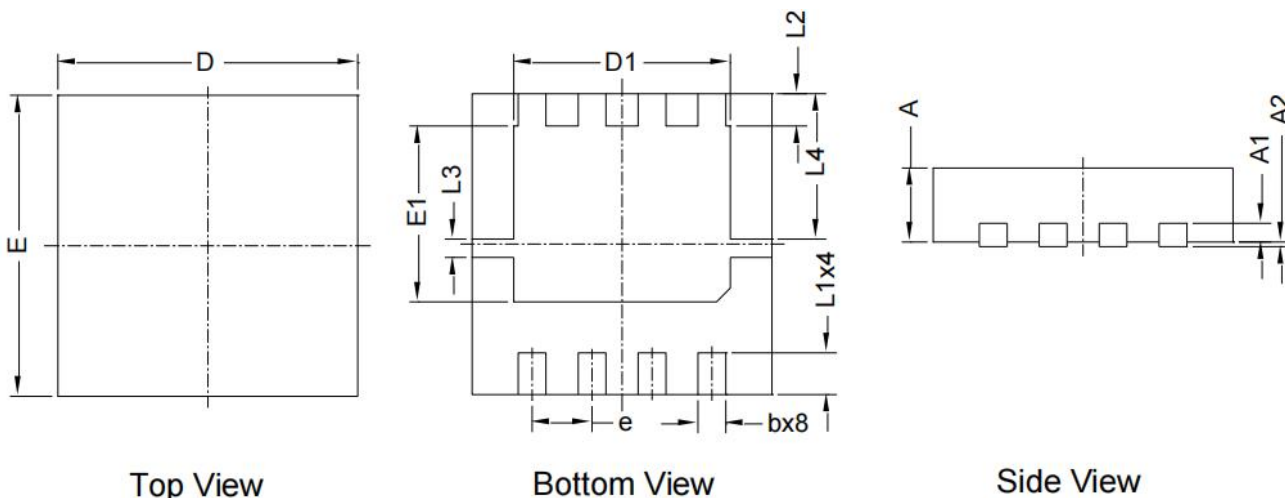


Figure 14. Safe Operation Area

DFN3.3*3.3-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
D	3.150	3.350	0.124	0.132
E	3.150	3.350	0.124	0.132
A	0.700	0.900	0.027	0.035
A1	0.200 BSC.		0.008 BSC.	
A2	0.000	0.100	0.000	0.004
D1	2.200	2.500	0.086	0.098
E1	1.800	2.000	0.071	0.079
L1	0.350	0.550	0.013	0.022
L2	0.350 BSC.		0.014 BSC.	
L3	0.200 BSC.		0.008 BSC.	
L4	1.570 BSC.		0.062 BSC.	
b	0.200	0.400	0.008	0.016
e	0.650 BSC.		0.026 BSC.	